

# NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 12. See TN3019A for characteristics.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V	
V <sub>CES</sub>	Collector-Base Voltage	50	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V	
Ic	Collector Current - Continuous	1.0	А	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics

Symbol	Characteristic	Мах	Units	
		BC337-16 / BC337-25		
P <sub>D</sub>	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	°C/W	

Electr	ical Characteristics TA =	= 25°C unless otherwise noted			
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	45		V
V <sub>(BR)CES</sub>	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	50		V
	Enducer Development development	$I_{E} = 100 \ \mu A, I_{C} = 0$	5.0		V
	Emitter-Base Breakdown Voltage	$E = 100 \mu R, R = 0$			
V <sub>(BR)EBO</sub> I <sub>CBO</sub>	Collector Cutoff Current	$ \begin{array}{l} V_{CB} = 20 \ V, \ I_{E} = 0, \ T_{A} = +25 \ ^{\circ}\text{C} \\ V_{CB} = 20 \ V, \ I_{E} = 0, \ T_{A} = +150 \\ ^{\circ}\text{C} \end{array} $		100 5.0	nA μA

## ON

h <sub>FE</sub>	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$			
		337-16	100	250	
		337-25	160	400	
		$V_{CE} = 1.0 \text{ V}, I_{C} = 500 \text{ mA}$	40		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		0.7	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	$V_{CE} = 1.0 \text{ V}, I_{C} = 500 \text{ mA}$		1.2	V

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